

15992 U.S. PTO  
121703

Atty. Dkt. No. 039153-0688  
(AMD H1726)

031088 U.S. PTO  
10/738496  
121703

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

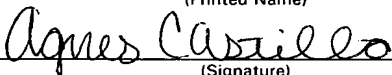
Applicant: Ihsan J. DJOMEHRI  
  
Title: STRAINED SILICON  
MOSFETS HAVING NMOS  
GATES WITH WORK  
FUNCTIONS FOR  
COMPENSATING NMOS  
THRESHOLD VOLTAGE  
SHIFT

Appl. No.: Unknown

Filing Date: Concurrently herewith

Examiner: Unknown

Art Unit: Unknown

<b>CERTIFICATE OF EXPRESS MAILING</b>	
I hereby certify that this correspondence is being deposited with the United States Postal Service's "Express Mail Post Office To Addressee" service under 37 C.F.R. § 1.10 on the date indicated below and is addressed to: Commissioner for Patents, PO Box 1450, Alexandria, Virginia 22313-1450.	
EV 060046336 US	December 17, 2003
(Express Mail Label Number)	(Date of Deposit)
Agnes Castillo	
(Printed Name)	
	
(Signature)	

**UTILITY PATENT APPLICATION**  
**TRANSMITTAL**

Mail Stop PATENT APPLICATION  
Commissioner for Patents  
PO Box 1450  
Alexandria, Virginia 22313-1450

Sir:

Transmitted herewith for filing under 37 C.F.R. § 1.53(b) is the nonprovisional utility patent application of:

Ihsan J. DJOMEHRI  
457 Sierra Vista Ave., #1  
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☐ Applicant claims small entity status under 37 CFR 1.27.

Enclosed are:

- ☒ Specification, Claim(s), and Abstract (23 pages).
- ☒ Formal drawings (13 sheets, Figures 1, 2, 3, 4a, 4b, 4c, 4d, 4e, 4f, 4g, 4h, 4i, 5a, 5b, 5c, 5d, 5e, 5f, 6, 7a, 7b, 7c, 7d, 7e, 7f, 6g, 8, 9, 10).
- ☒ Declaration and Power of Attorney (8 pages).
- ☒ Assignment of the invention to Advanced Micro Devices, Inc..
- ☒ Assignment Recordation Cover Sheet.
- ☒ Check in the amount of \$40.00 for Assignment recordation.
- ☐ Small Entity statement.
- ☒ Request for application not to be published with certification under 35 USC 122(b)(2)(B)(i).
- ☐ Information Disclosure Statement.
- ☐ Form PTO/SB/08 with copies of \_\_\_\_ listed reference(s).
- ☒ Application Data Sheet (37 CFR 1.76).
- ☐ Claim for Convention Priority.

The filing fee is calculated below:

	Claims as Filed		Included in Basic Fee		Extra Claims		Rate		Fee Totals
Basic Fee							\$770.00	=	\$770.00
Total	22	-	20	=	2	x	\$18.00	=	\$36.00
Claims:									
Independents	4	-	3	=	1	x	\$86.00	=	\$86.00
:									
If any Multiple Dependent Claim(s) present:						+	\$290.00	=	\$0.00
							SUBTOTAL:	=	\$892.00
[   ]							Small Entity Fees Apply (subtract ½ of above):	=	\$0.00
							TOTAL FILING FEE:	=	\$892.00

[ X ] Two checks in the amounts of \$892.00 for the filing fee and \$40.00 for the assignment recordation fee are enclosed.

[ X ] The Commissioner is hereby authorized to charge any additional fees which may be required regarding this application under 37 C.F.R. §§ 1.16-1.17, or credit any overpayment, to Deposit Account No. 50-0872. Should no proper payment be enclosed herewith, as by a check being in the wrong amount, unsigned, post-dated, otherwise improper or informal or even entirely missing, the Commissioner is authorized to charge the unpaid amount to Deposit Account No. 50-0872.

Please direct all correspondence to the undersigned attorney or agent at the address indicated below.

Respectfully submitted,

Date: December 17, 2003

By 

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Ronald Coslick  
Attorney for Applicant  
Registration No. 36,489

***IN THE UNITED STATES PATENT AND TRADEMARK OFFICE***

Applicant: Ihsan J. DJOMEHRI  
Title: STRAINED SILICON MOSFETS HAVING NMOS GATES WITH WORK  
FUNCTIONS FOR COMPENSATING NMOS THRESHOLD VOLTAGE  
SHIFT  
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Examiner: Unknown  
Art Unit: Unknown

**REQUEST AND CERTIFICATION UNDER 35 U.S.C. 122(b)(2)(B)(i)**

Commissioner for Patents  
PO Box 1450  
Alexandria, Virginia 22313-1450

Sir:

Applicants hereby certify that the invention disclosed in the attached application has not and will not be the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing. Applicants hereby request that the attached application not be published under 35 U.S.C. 122(b).

Respectfully submitted,

Date: December 17, 2003

By 

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Customer Number: 23392  
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